

# Silicon – Diode Pair

## **FA2325E**

(Diode Pair FD2389)

150V/150mA

# DATASHEET

OEM – Fairchild

Source: Fairchild Databook 1978

# FA SERIES

## PAIR, QUAD AND BRIDGE DIODE ASSEMBLIES

SILICON PLANAR EPITAXIAL

- $\Delta V_F$  ... Down to 3 mV (MAX)
- $\Delta I_R$  ... Down to 10 nA (MAX)

**GENERAL DESCRIPTION**

The FA series of diode assemblies are pairs, quads and bridges composed of individual glass diodes encapsulated in epoxy packages. The pairs and quads are also available in unencapsulated form, the diodes being securely taped together for shipment.

These assemblies feature very tight matching characteristics over broad temperature and current ranges.

**ABSOLUTE MAXIMUM RATINGS (Note 1)**

**Temperatures**

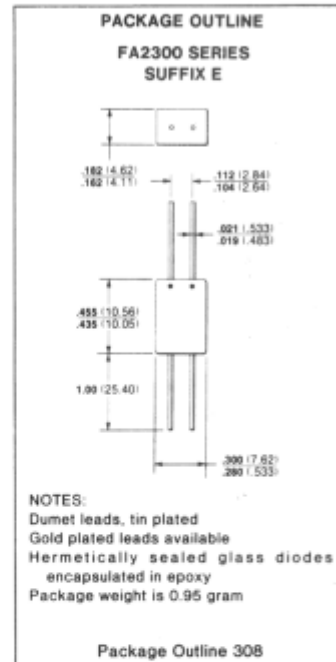
|  |                 |
|--|-----------------|
| Storage Temperature Range              | -65°C to +200°C |
| Maximum Junction Operating Temperature | +175°C          |
| Lead Temperature                       | +260°C          |

**Power Dissipation (Note 2)**

|   |            |
|---|------------|
| Maximum Total Power Dissipation at 25°C Ambient |            |
| Each Diode                                      | 250 mW     |
| Encapsulated Package                            | 500 mW     |
| Linear Power Derating factor (from 25°C)        |            |
| Each Diode                                      | 1.67 mW/°C |
| Encapsulated Package                            | 3.33 mW/°C |

**Maximum Voltage and Currents**

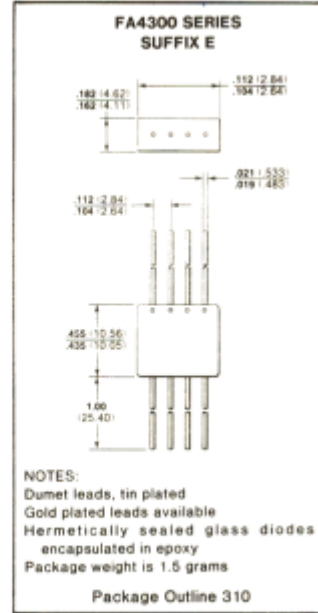
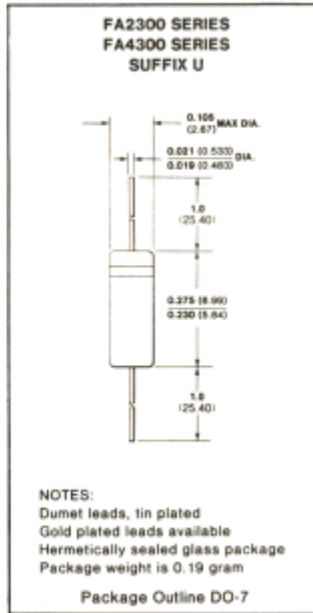
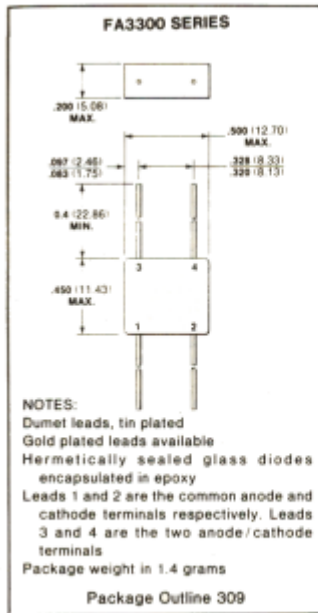
| Basic Diode (See Specification below)     | FD1389 | FD2389 | FD3389 | FD6389 |
|---|--------|--------|--------|--------|
| WIV Working Inverse Voltage               | 75 V   | 150 V  | 125 V  | 50 V   |
| $I_O$ Average Rectified Current           | 100 mA | 100 mA | 150 mA | 200 mA |
| $I_F$ Continuous Forward Current          | 150 mA | 150 mA | 225 mA | 300 mA |
| $i_f$ Recurrent Peak Forward Current      | 300 mA | 300 mA | 450 mA | 600 mA |
| $i_{f(surge)}$ Peak Forward Surge Current |        |        |        |        |
| Pulse width = 1.0 s                       | 1.0 A  | 1.0 A  | 1.0 A  | 1.0 A  |
| Pulse width = 1.0 $\mu$ s                 | 4.0 A  | 4.0 A  | 4.0 A  | 4.0 A  |



**MATCHING CHARACTERISTICS (Apply over temperature range of -55°C to +100°C)**

| Basic Diode (See Specification below) | Forward Current Matching Range (Notes 4 & 6) | Reverse Current Match ( $\Delta I_R$ Maximum) (Note 3) | Forward Voltage Match ( $\Delta V_F$ Maximum) | Assembly Type Number      |                             |                           |                             |                    |
|---------------------------------------|--|--|---|---------------------------|-----------------------------|---------------------------|-----------------------------|--------------------|
|                                       |  |  |   | Encap-<br>sulated<br>Pair | Unencap-<br>sulated<br>Pair | Encap-<br>sulated<br>Quad | Unencap-<br>sulated<br>Quad | Bridge<br>(Note 6) |
| FD1389                                | 10 $\mu$ A to 1.0 mA                         |  | 3.0 mV  | FA2310E                   | FA2310U                     | FA4310E                   | FA4310U                     | FA3310             |
| FD1389                                | 10 $\mu$ A to 1.0 mA                         |  | 10 mV   | FA2311E                   | FA2311U                     | FA4311E                   | FA4311U                     | FA3311             |
| FD1389                                | 1.0 mA to 10 mA                              |  | 5.0 mV  | FA2312E                   | FA2312U                     | FA4312E                   | FA4312U                     | FA3312             |
| FD1389                                | 1.0 mA to 10 mA                              |  | 15 mV   | FA2313E                   | FA2313U                     | FA4313E                   | FA4313U                     | FA3313             |
| FD2389                                | 10 $\mu$ A to 1.0 mA                         |  | 3.0 mV  | FA2320E                   | FA2320U                     | FA4320E                   | FA4320U                     | FA3320             |
| FD2389                                | 10 $\mu$ A to 1.0 mA                         |  | 10 mV   | FA2321E                   | FA4321U                     | FA4321E                   | FA4321U                     | FA3321             |
| FD2389                                | 1.0 mA to 10 mA                              |  | 5.0 mV  | FA2322E                   | FA2322U                     | FA4322E                   | FA4322U                     | FA3322             |
| FD2389                                | 1.0 mA to 10 mA                              |  | 15 mV   | FA2323E                   | FA2323U                     | FA4323E                   | FA4323U                     | FA3323             |
| FD2389                                | 1.0 mA to 10 mA                              |  | 10 mV   | FA2324E                   | FA2324U                     | FA4324E                   | FA4324U                     | FA3324             |
| FD2389                                | 10 mA to 100 mA                              |  | 20 mV   | FA2325E                   | FA2325U                     | FA4325E                   | FA4325U                     | FA3325             |
| FD3389                                | 10 $\mu$ A to 1.0 mA                         | (2.0 + 0.064 $V_R$ ) nA                                | 10 mV   | FA2330E                   | FA2330U                     | FA4330E                   | FA4330U                     | FA3330             |
| FD3389                                | 1.0 mA to 10 mA                              | (2.0 + 0.064 $V_R$ ) nA                                | 15 mV   | FA2331E                   | FA2331U                     | FA4331E                   | FA4331U                     | FA3331             |
| FD3389                                | 10 mA to 100 mA                              | (2.0 + 0.064 $V_R$ ) nA                                | 20 mV   | FA2332E                   | FA2332U                     | FA4332E                   | FA4332U                     | FA3332             |
| FD3389                                | 10 $\mu$ A to 1.0 mA                         | (4.0 + 0.128 $V_R$ ) nA                                | 10 mV   | FA2333E                   | FA2333U                     | FA4333E                   | FA4333U                     | FA3333             |
| FD3389                                | 1.0 mA to 10 mA                              | (4.0 + 0.128 $V_R$ ) nA                                | 15 mV   | FA2334E                   | FA2334U                     | FA4334E                   | FA4334U                     | FA3334             |
| FD3389                                | 10 mA to 100 mA                              | (4.0 + 0.128 $V_R$ ) nA                                | 20 mV   | FA2335E                   | FA2335U                     | FA4335E                   | FA4335U                     | FA3335             |
| FD6389                                | 10 mA to 100 mA                              |  | 10 mV   | FA2360E                   | FA2360U                     | FA4360E                   | FA4360U                     | FA3360             |
| FD6389                                | 10 mA to 100 mA                              |  | 20 mV   | FA2361E                   | FA2361U                     | FA4361E                   | FA4361U                     | FA3361             |

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BASIC DIODE ELECTRICAL CHARACTERISTICS (25°C Ambient Temperature unless otherwise noted)

| SYMBOL   | CHARACTERISTIC        | FD1389 |            | FD2389 |  | FD3389 |  | FD6389 |  | UNITS         | TEST CONDITIONS   |
|----------|-----------------------|--------|------------|--------|--|--------|--|--------|--|---------------|---|
|          |                       | MIN    | MAX        | MIN    | MAX  | MIN    | MAX  | MIN    | MAX  |               |   |
| BV       | Breakdown Voltage     | 100    |            | 200    |  | 150    |  | 75     |  | V             | $I_R = 5.0 \mu A$<br>$I_R = 100 \mu A$  |
| $I_R$    | Reverse Current       |        | 100<br>100 |        | 100<br>100   |        | 1.0<br>3.0   |        | 100<br>100   | nA<br>$\mu A$ | $V_R = WIV$<br>$V_R = WIV, T_A = 150^\circ C$   |
| $V_F$    | Forward Voltage       |        |            |        | 1.000<br>0.925<br>0.860<br>0.790<br>0.875<br>0.800<br>0.725<br>0.670 |        | 1.000<br>0.930<br>0.880<br>0.840<br>0.810<br>0.770<br>0.730<br>0.710 |        | 1.000<br>0.920<br>0.860<br>0.790<br>0.750<br>0.710<br>0.670<br>0.630 | V             | $I_F = 200 \text{ mA}$<br>$I_F = 100 \text{ mA}$<br>$I_F = 50 \text{ mA}$<br>$I_F = 20 \text{ mA}$<br>$I_F = 10 \text{ mA}$<br>$I_F = 5.0 \text{ mA}$<br>$I_F = 2.0 \text{ mA}$<br>$I_F = 1.0 \text{ mA}$ |
| C        | Capacitance (Note 5)  |        | 2.0        |        | 5.0  |        | 6.0  |        | 3.0  | pF            | $V_R = 0, f = 1 \text{ MHz}$  |
| $t_{rr}$ | Reverse Recovery Time |        | 4.0        |        | 50   |        |  |        | 4.0  | ns            | $I_F = I_R = 10 \text{ mA}$<br>Recover to 1.0 mA<br>$I_F = I_R = 30 \text{ mA}$<br>Recover to 1.0 mA<br>$I_F = I_R = 200 \text{ mA}$<br>Recover to 20 mA  |

- NOTES:
- These are limiting values above which life or satisfactory performance may be impaired.
  - These are steady state limits. The factory should be consulted on applications involving pulsed or low duty-cycle operation.
  - The Reverse Current Match ( $\Delta I_R$ ) is the difference in reverse current between the diode having the highest  $I_R$  and that having the lowest  $I_R$  in a given assembly. The reverse voltage ( $V_R$ ) in the  $\Delta I_R$  calculation can be any value up to 125 V. For example, the maximum  $\Delta I_R$  for an FA2330E at  $V_R$  of 10 V is  $(2.0 \pm 0.054 \times 10) \text{ nA}$  or 2.84 nA.
  - The Forward Current Matching Ranges between 10  $\mu A$  and 10 mA may be applied either as a dc current or a pulse current. Above 10 mA, however, the matching characteristics are guaranteed only for low duty cycle ( $\leq 1\%$ ) pulse current. Conditions of test are shown in the characteristic curve and test circuit section of this book (see Note 7).
  - Capacitance cannot be monitored independently on each diode in a bridge configuration. In measuring capacitance in a bridge, the limit is 4/3 that shown in the basic diode electrical characteristics.
  - For matched bridges, the forward current range specified is per leg. Therefore, twice the current specified is applied to the assembly.
  - For product family characteristics curves for the basic diodes used in the assemblies, refer to the following parts of Section 4:  
FD1389 D4  
FD2389 D1  
FD3389 D2  
FD6389 D4  
For test circuits, refer to Chapter 4, D18.

**CURVE SET NUMBER D1**  
HIGH VOLTAGE SMALL SIGNAL DIODE

**TYPICAL ELECTRICAL CHARACTERISTIC CURVES**  
AT 25°C AMBIENT TEMPERATURE UNLESS OTHERWISE NOTED

